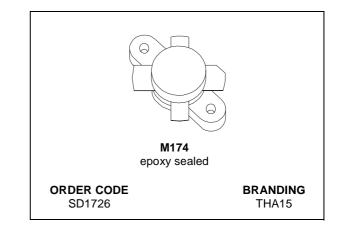


# SD1726 (THA15) RF & MICROWAVE TRANSISTORS HF SSB APPLICATIONS

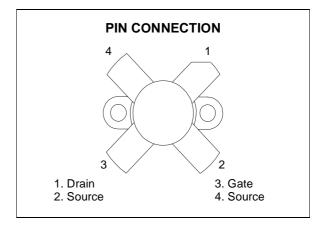
### FEATURES

- OPTIMIZED FOR SSB
- 30 MHz
- 50 V
- IMD-30 dB
- COMMON EMITTER
- GOLD METALLIZATION
- POUT = 150 W PEP MIN. WITH 14 dB GAIN



#### DESCRIPTION

The SD1726 is a 50 V epitaxial silicon NPN planar transistor designed primarily for SSB communications. This device utilizes emitter ballasting to achieve extreme ruggedness under severe operating conditions.



# **ABSOLUTE MAXIMUM RATINGS** (T<sub>CASE</sub> = 25 $^{\circ}$ C)

Symbol	Parameter	Value	Unit
V <sub>CBO</sub>	Collecto-Base Voltage	110	V
V <sub>CEO</sub>	Collector-Emitter Voltage	55	V
V <sub>EBO</sub>	Emitter-Base Voltage	4.0	V
Ι <sub>C</sub>	Drain Current	20	А
P <sub>DISS</sub>	Power Dissipation	318	W
Tj	Max. Operating Junction Temperature	+200	°C
T <sub>STG</sub>	Storage Temperature	-65 to +150	°C

#### THERMAL DATA

$R_{th(j-c)}$ Junction -Case Thermal Resistance at $T_{CASE} = 70 \degree C$	0.75	°C/W
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# SD1726 (THA15)

# ELECTRICAL SPECIFICATION (T<sub>CASE</sub> = 25 °C)

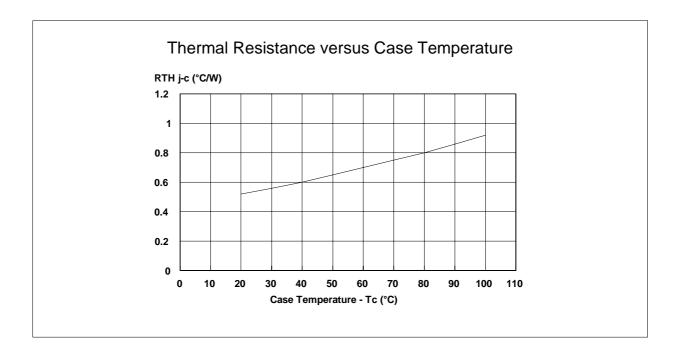
# STATIC

Symbol	Test Conditions	Min.	Тур.	Max.	Unit
BV <sub>CBO</sub>	$I_C = 100 \text{ mA}$ $I_E = 0 \text{ mA}$	110			V
BV <sub>CES</sub>	I <sub>C</sub> = 100 mA V <sub>BE</sub> = 0 V	110			V
BV <sub>CEO</sub>	$I_{\rm C} = 100 \text{ mA}$ $I_{\rm B} = 0 \text{ mA}$	55			V
BV <sub>EBO</sub>	$I_E = 10 \text{ mA}$ $I_C = 0 \text{ mA}$	4.0			V
I <sub>CEO</sub>	$V_{CE} = 30 \text{ V}$ $I_E = 0 \text{ mA}$			5	mA
I <sub>CES</sub>	$V_{CE} = 60 \text{ V}$ $I_E = 0 \text{ mA}$			5	mA
h <sub>FE</sub>	$V_{CE} = 6 V I_{C} = 1.4 A$	18		43.5	

#### DYNAMIC

Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Pout	$V_{CE} = 50 \text{ V}$ $I_{CQ} = 100 \text{ mA}$ f = 30 MHz	150			W
G <sub>P</sub> *	V <sub>CE</sub> = 50 V I <sub>CQ</sub> = 100 mA P <sub>OUT</sub> = 150 W PEP	14			dB
IMD*	V <sub>CE</sub> = 50 V I <sub>CQ</sub> = 100 mA P <sub>OUT</sub> = 150 W PEP			-30	dBc
ηD <sup>*</sup>	$V_{CE} = 50 \text{ V}$ $I_{CQ} = 100 \text{ mA}$ $P_{OUT} = 150 \text{ W PEP}$	37			%
G <sub>OB</sub>	$V_{CB} = 50 \text{ V} \text{ f} = 1 \text{ MHz}$			220	рF

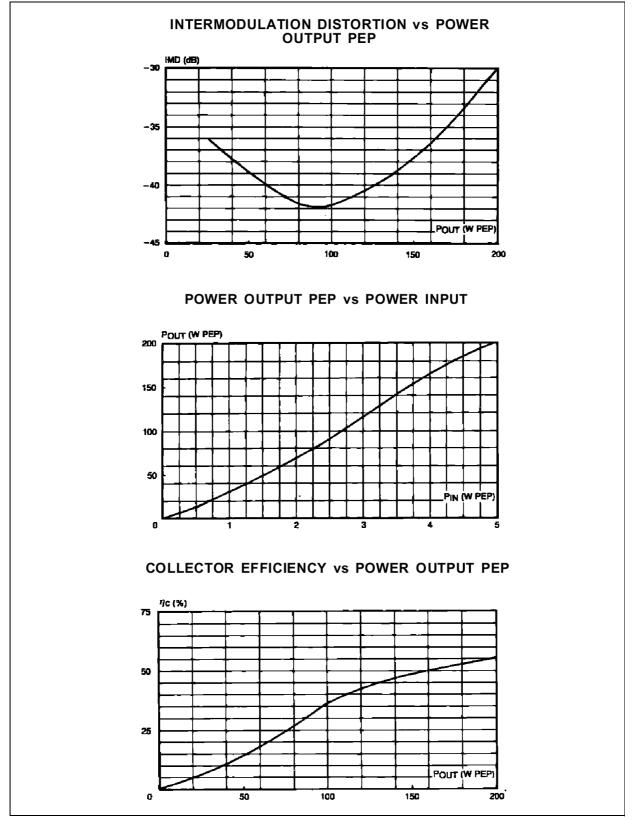
Note: The SD1726 is also usable in Class A at 40 V. Typical performance is:  $P_{OUT} = 30 \text{ W PEP}, G_P = 14 \text{ dB}, \text{IMD} = -40 \text{ dBc}$ \* f<sub>1</sub> = 30.00 MHz; f<sub>2</sub> = 30.001 MHz



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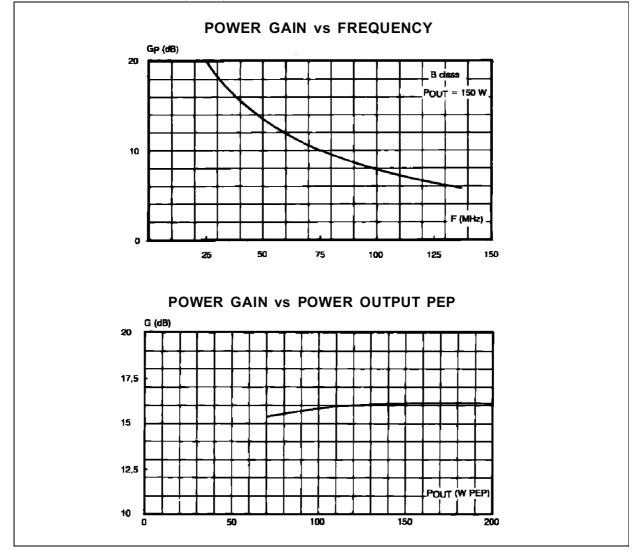
# TYPICAL PERFORMANCE

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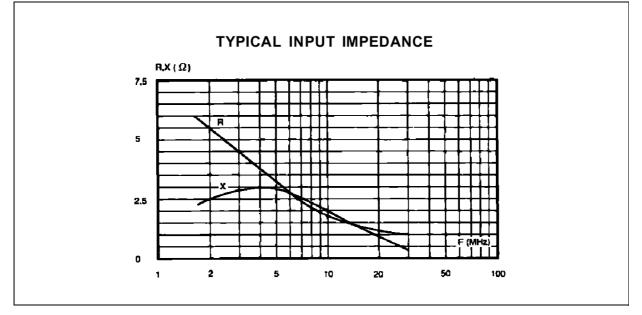
# SD1726 (THA15)

# TYPICAL PERFORMANCE (cont'd)

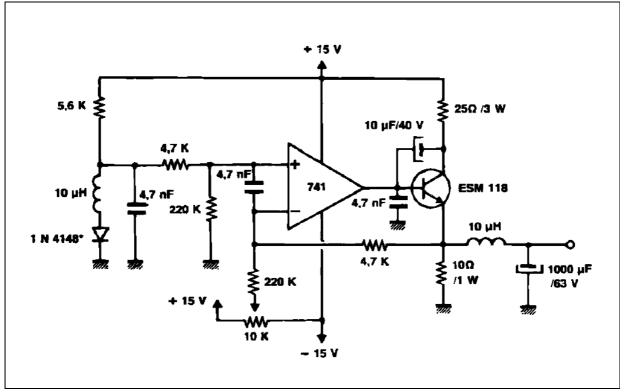




# **IMPEDENCE DATA**



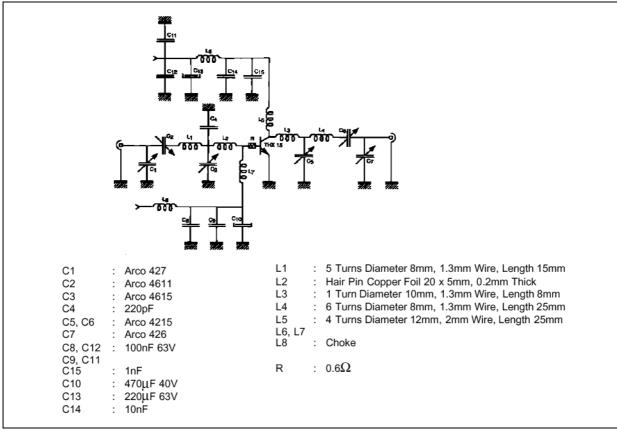
**BIAS CIRCUIT** 



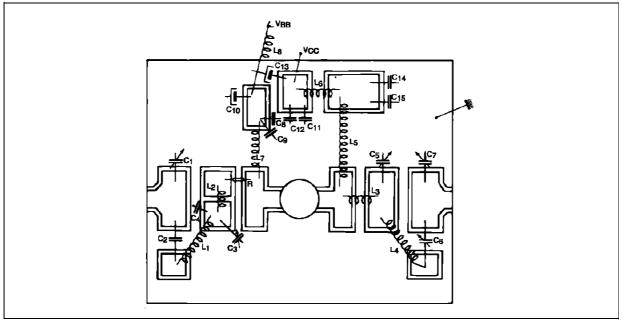
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# SD1726 (THA15)

#### **TEST CIRCUIT - CLASS AB - 30 MHz**



#### **MOUNTING CIRCUIT - CLASS AB - 30 MHz**

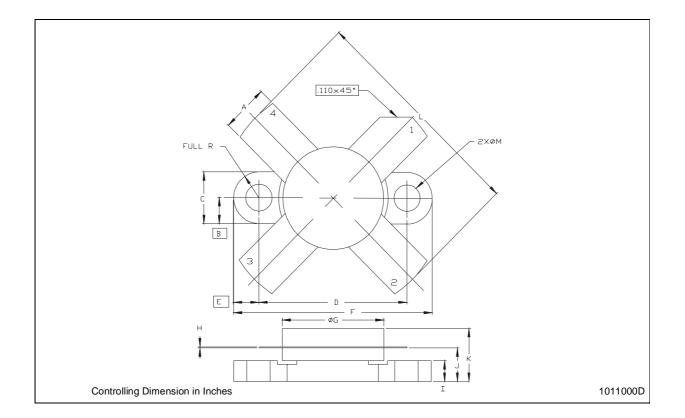


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6/8

DIM.	mm			Inch			
	MIN.	TYP.	MAX	MIN.	TYP.	MAX	
А	5.56		5.584	0.219		0.230	
В		3.18			0.125		
С	6.22		6.48	0.245		0.255	
D	18.28		18.54	0.720		0.730	
E		3.18			0.125		
F	24.64		24.89	0.970		0.980	
G	12.57		12.83	0.495		0.505	
Н	0.08		0.18	0.003		0.007	
I	2.11		3.00	0.083		0.118	
J	3.81		4.45	0.150		0.175	
К			7.11			0.280	
L	25.53		26.67	1.005		1.050	
М	3.05		3.30	0.120		0.130	

M174 (.500 DIA 4/L N/HERM W/FLG) MECHANICAL DATA



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